## NSN 5962-01-293-4116

Memory Microcircuit - Page 1 of 1

**Fiig:** A458a0



View Online at https://aerobasegroup.com/nsn/5962-01-293-4116

Body Length:
Between 1.230 inches and 1.285 inches
Body Width:
Between 0.510 inches and 0.545 inches
Body Height:
Between 0.090 inches and 0.210 inches
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and burn in and programmable and bipolar and high performance
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
14 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
40.00 nanoseconds propagation delay time, low to high level output and 40.00 nanoseconds propagation delay time, high to low leve
output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli